Data Sheet

September 13, 2005

FN4780.3

## Radiation Hardened 2.5V Reference

The Star\*Power Radiation Hardened IS-1009RH is a 2.5V shunt regulator diode designed to provide a stable 2.5V reference over a wide current range.

The device is designed to maintain stability over the full military temperature range and over time. The 0.2% reference tolerance is achieved by on-chip trimming.

An adjustment terminal is provided to allow for the calibration of system errors. The use of this terminal to adjust the reference voltage does not effect the temperature coefficient.

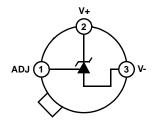
Constructed with the Intersil dielectrically isolated EBHF process, these devices are immune to Single Event Latch-up and have been specifically designed to provide highly reliable performance in harsh radiation environments.

Specifications for Rad Hard QML devices are controlled by the Defense Supply Center in Columbus (DSCC). The SMD numbers listed here must be used when ordering.

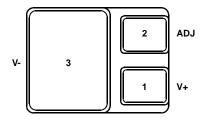
Detailed Electrical Specifications for these devices are contained in SMD 5962-00523.

## **Pinouts**

## IS2-1009RH (TO-206AB CAN) BOTTOM VIEW



## ISYE-1009RH (SMD.5) BOTTOM VIEW



## **Features**

- Electrically Screened to SMD # 5962-00523
- QML Qualified per MIL-PRF-38535 Requirements
- Radiation Environment

  - Latch-up Immune . . . . . . . Dielectrically Isolated
- Reverse Breakdown Voltage (V<sub>Z</sub>) . . . . . . . . . 2.5V
- Change in  $V_Z$  vs. Current (400 $\mu A$  to 10mA). . . . . . . 6mV
- Change in V<sub>Z</sub> vs. Temp (-55°C to 125°C) . . . . . . . 15mV
- Max Reverse Breakdown Current . . . . . . . . . 20mA
- Interchangeable with 1009 and 136 Industry Types

# **Applications**

- Power Supply Monitoring
- · Reference for 5V Systems
- A/D and D/A Reference

# Ordering Information

ORDERING NUMBER	INTERNAL MKT. NUMBER	TEMP. RANGE (°C)
5962F0052301VXC	IS2-1009RH-Q	-55 to 125
5962F0052301QXC	IS2-1009RH-8	-55 to 125
5962F0052301VYC	ISYE-1009RH-Q	-55 to 125
5962F0052301QYC	ISYE-1009RH-8	-55 to 125
IS2-1009RH/Proto	IS2-1009RH/Proto	-55 to 125
ISYE-1009RH/Proto	ISYE-1009RH/Proto	-55 to 125

## Die Characteristics

## **DIE DIMENSIONS**

1270μm x 1778μm (50 mils x 70 mils) Thickness: 483μm  $\pm 25.4$ μm (19 mils  $\pm 1$  mil)

## **INTERFACE MATERIALS**

#### Glassivation

Type: Nitride ( $Si_3N_4$ ) over Silox ( $SiO_2$ ) Nitride Thickness:  $4.0k\mathring{A} \pm 1.0k\mathring{A}$  Silox Thickness:  $12.0k\mathring{A} \pm 4.0k\mathring{A}$ 

## Top Metallization

Type: AlSiCu

Thickness: 16.0kÅ ±2kÅ

## Substrate

EBHF, Dielectric Isolation

# Metallization Mask Layout

## **Backside Finish**

Silicon

## ASSEMBLY RELATED INFORMATION

## **Substrate Potential**

Unbiased (DI)

## ADDITIONAL INFORMATION

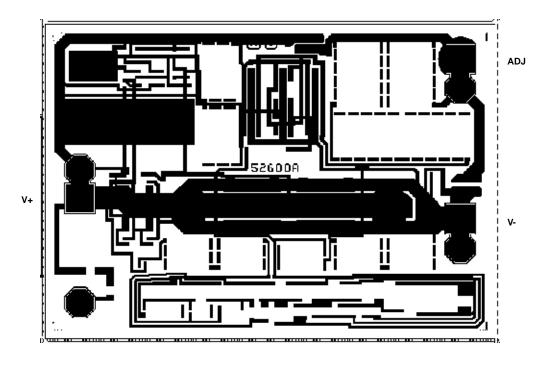
## **Worst Case Current Density**

 $<1.0 \times 10^5 \text{ A/cm}^2$ 

## **Transistor Count**

26

IS-1009RH



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